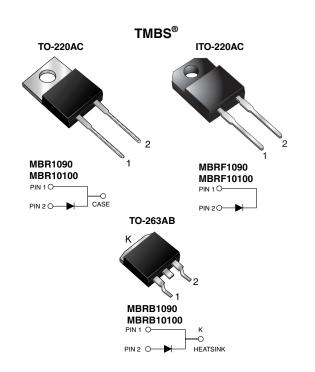


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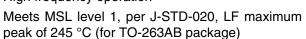
## **High-Voltage Schottky Rectifier**



| PRIMARY CHARACTERISTICS |             |  |  |  |  |
|-------------------------|-------------|--|--|--|--|
| I <sub>F(AV)</sub> 10 A |             |  |  |  |  |
| V <sub>RRM</sub>        | 90 V, 100 V |  |  |  |  |
| I <sub>FSM</sub>        | 150 A       |  |  |  |  |
| V <sub>F</sub>          | 0.65 V      |  |  |  |  |
| T <sub>J</sub> max.     | 150 °C      |  |  |  |  |

#### **FEATURES**

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- · High forward surge capability
- High frequency operation



- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

#### **MECHANICAL DATA**

Case: TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94 V-0 flammability

rating

Base P/N-E3 - RoHS compliant, commercial grade

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)                    |                                   |                        |          |      |  |  |
|--|-----------------------------------|------------------------|----------|------|--|--|
| PARAMETER  | SYMBOL                            | MBR1090                | MBR10100 | UNIT |  |  |
| Maximum repetitive peak reverse voltage  | V <sub>RRM</sub>                  | V <sub>RRM</sub> 90 10 |          | V    |  |  |
| Working peak reverse voltage   | V <sub>RWM</sub>                  | 90                     | 100      | V    |  |  |
| Maximum DC blocking voltage  | V <sub>DC</sub>                   | 90                     | 100      | V    |  |  |
| Maximum average forward rectified current at T <sub>C</sub> = 133 °C               | I <sub>F(AV)</sub>                | 10                     |          | А    |  |  |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load | I <sub>FSM</sub>                  | 150                    |          | А    |  |  |
| Non-repetitive avalanche energy at $T_J = 25$ °C, $L = 60$ mH                      | E <sub>AS</sub>                   | 130                    |          | mJ   |  |  |
| Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C ± 2 °C  | I <sub>RRM</sub>                  | 0.5                    |          | А    |  |  |
| Voltage rate of change (rated V <sub>R</sub> )                                     | dV/dt                             | 10 000                 |          | V/µs |  |  |
| Isolation voltage (ITO-220AC only) From terminal to heatsink t = 1 min             | V <sub>AC</sub>                   | 1500                   |          | V    |  |  |
| Operating junction and storage temperature range                                   | T <sub>J</sub> , T <sub>STG</sub> | - 65 to + 150          |          | °C   |  |  |

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| <b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted) |   |   |                 |                      |          |       |      |
|---|---|---|-----------------|----------------------|----------|-------|------|
| PARAMETER   | TEST CONDITIONS   |   | TEST CONDITIONS |                      | SYMBOL   | VALUE | UNIT |
| Maximum instantaneous forward voltage (1)   | I <sub>F</sub> = 10 A<br>I <sub>F</sub> = 10 A<br>I <sub>F</sub> = 20 A | $T_{C} = 25 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$ $T_{C} = 125 ^{\circ}\text{C}$ | V <sub>F</sub>  | 0.80<br>0.65<br>0.75 | V        |       |      |
| Maximum reverse current at working peak reverse voltage (2)                       |   | $T_J = 25 ^{\circ}\text{C}$<br>$T_J = 100 ^{\circ}\text{C}$                                 | I <sub>R</sub>  | 100<br>6.0           | μA<br>mA |       |      |

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu$ s pulse width, 1 % duty cycle

 $^{(2)}$  Pulse test: Pulse width  $\leq$  40 ms

| THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted) |  |           |          |           |      |
|---|--|-----------|----------|-----------|------|
| PARAMETER   | SYMBOL   | MBR       | MBRF     | MBRB      | UNIT |
| Typical thermal resistance  | $egin{array}{c} R_{	hetaJA} \ R_{	hetaJC} \end{array}$ | 60<br>2.0 | -<br>3.5 | 60<br>2.0 | °C/W |

| ORDERING INFORMATION (Example) |                 |                 |              |               |               |  |  |
|--------------------------------|-----------------|-----------------|--------------|---------------|---------------|--|--|
| PACKAGE                        | PREFERRED P/N   | UNIT WEIGHT (g) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE |  |  |
| TO-220AC                       | MBR10100-E3/4W  | 1.845           | 4W           | 50/tube       | Tube          |  |  |
| ITO-220AC                      | MBRF10100-E3/4W | 1.661           | 4W           | 50/tube       | Tube          |  |  |
| TO-263AB                       | MBRB10100-E3/4W | 1.384           | 4W           | 50/tube       | Tube          |  |  |
| TO-263AB                       | MBRB10100-E3/8W | 1.384           | 8W           | 800/reel      | Tape and reel |  |  |

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

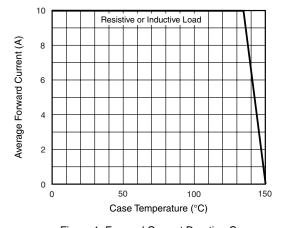


Figure 1. Forward Current Derating Curve

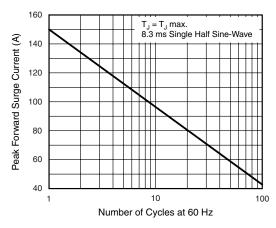


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current



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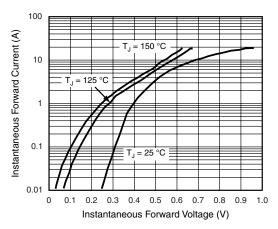


Figure 3. Typical Instantaneous Forward Characteristics

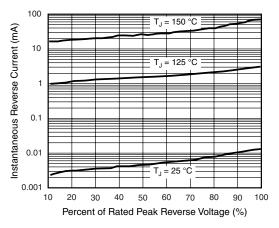


Figure 4. Typical Reverse Characteristics

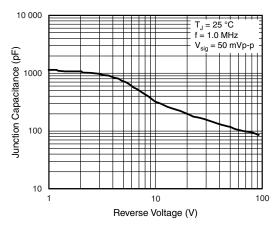


Figure 5. Typical Junction Capacitance

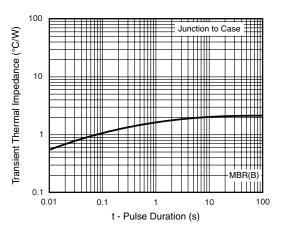


Figure 6. Typical Transient Thermal Impedance

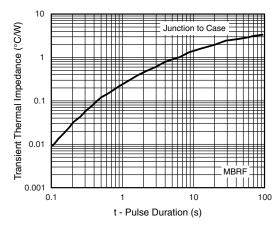
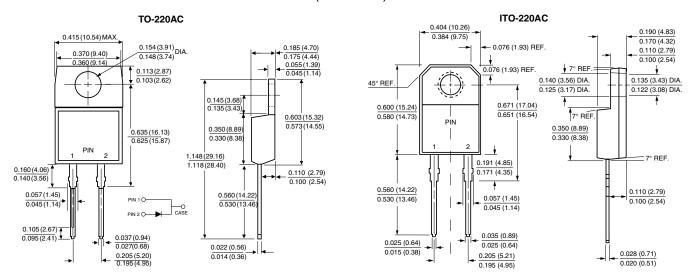


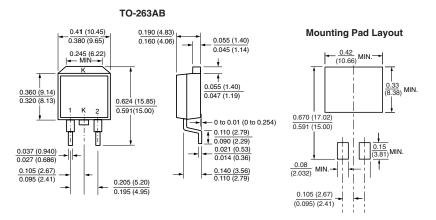
Figure 7. Typical Transient Thermal Impedance

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#### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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